

# GB6S THRU GB10S

**SINGLE PHASE GLASS PASSIVATED  
SURFACE MOUNT FLAT BRIDGE RECTIFIER**  
VOLTAGE: 600 to 1000V      CURRENT: 0.8A

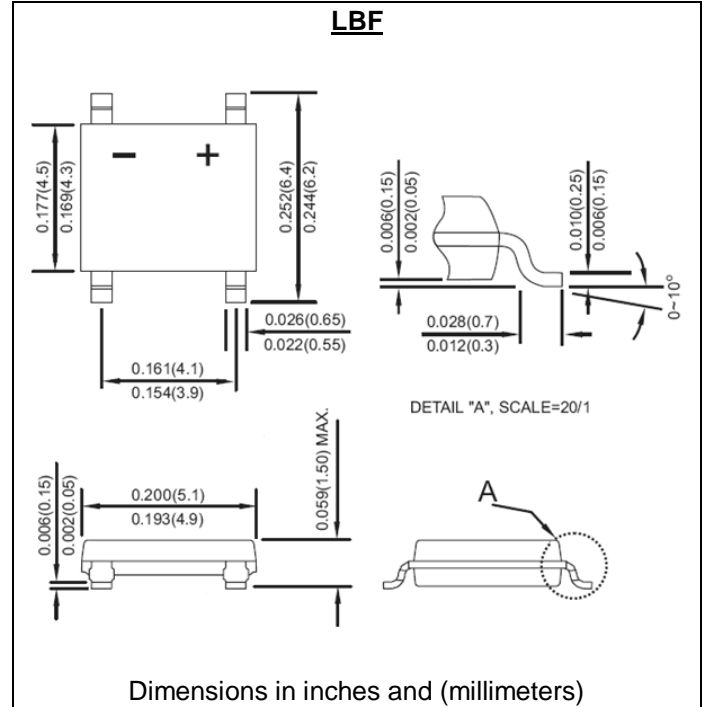


## FEATURE

- Ideal for printed circuit board
- Glass passivated chip
- Reliable low cost construction utilizing molded plastic technique
- High surge current capability
- Small size, simple installation
- High temperature soldering guaranteed: 260°C/10 seconds

## MECHANICAL DATA

- Terminal: Plated leads solderable per J-STD-002
- Case: UL-94 Class V-0 recognized Flame Retardant Epoxy
- Polarity: Polarity symbol marked on body



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half -wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

|   | Symbol                                     | GB6S         | GB8S | GB10S | units |
|---|--|--------------|------|-------|-------|
| Maximum Recurrent Peak Reverse Voltage  | V <sub>rrm</sub>                           | 600          | 800  | 1000  | V     |
| Maximum RMS Voltage   | V <sub>rms</sub>                           | 420          | 560  | 700   | V     |
| Maximum DC blocking Voltage   | V <sub>dc</sub>                            | 600          | 800  | 1000  | V     |
| Maximum Average Forward Rectified Current<br>on glass-epoxy P.C.B.                | I <sub>f(av)</sub>                         | 0.8          |      |       | A     |
| Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load | I <sub>fsm</sub>                           | 30.0         |      |       | A     |
| Maximum Instantaneous Forward Voltage at forward current 0.4A                     | V <sub>f</sub>                             | 0.95         |      |       | V     |
| Maximum DC Reverse Current<br>at rated DC blocking voltage                        | I <sub>r</sub>                             | 5.0<br>100.0 |      |       | μA    |
| Typical Thermal resistance<br>junction to lead<br>on glass-epoxy P.C.B.           | R <sub>th(jl)</sub><br>R <sub>th(ja)</sub> | 25<br>80     |      |       | °C/W  |
| Storage and Operating Junction Temperature Range                                  | T <sub>stg, Tj</sub>                       | -55 to +150  |      |       | °C    |

Note:

## RATINGS AND CHARACTERISTIC CURVES GB6S THRU GB10S

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

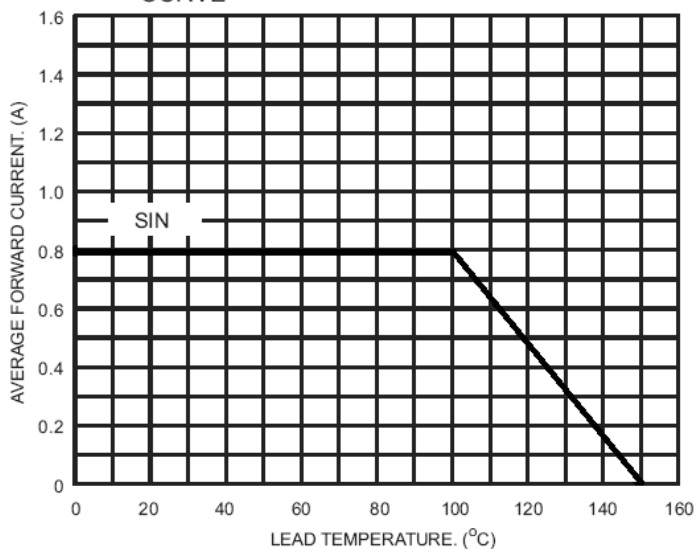


FIG.2- TYPICAL FORWARD CHARACTERISTICS

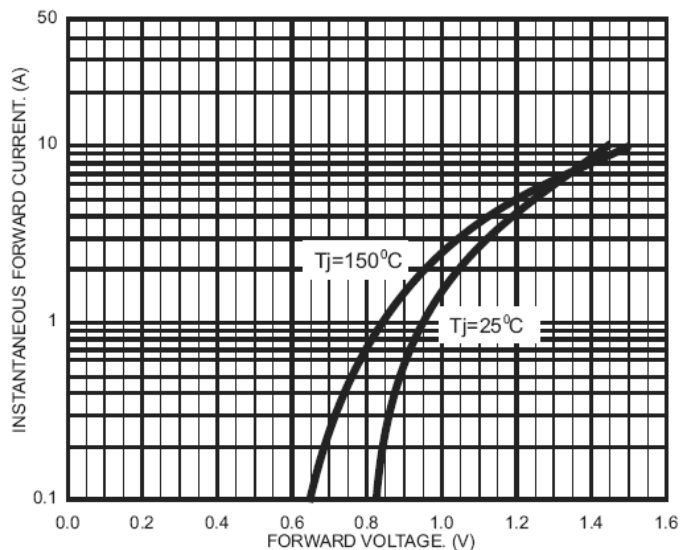


FIG.3- MAXIMUM FORWARD CURRENT DERATING CURVE

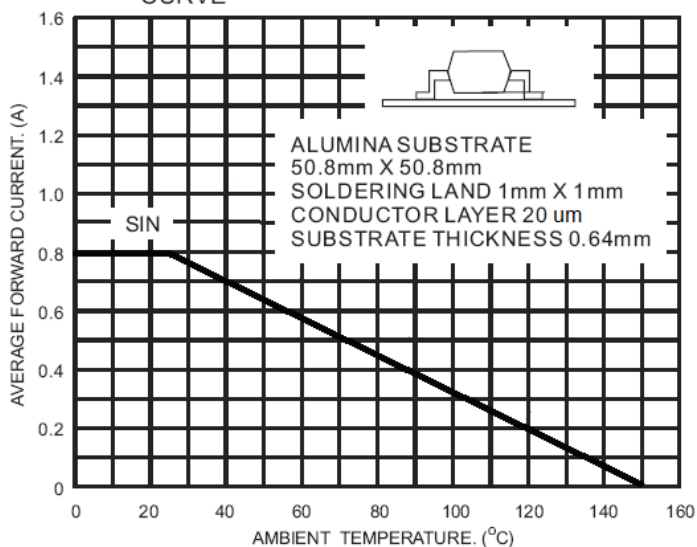


FIG.4- FORWARD POWER DISSIPATION

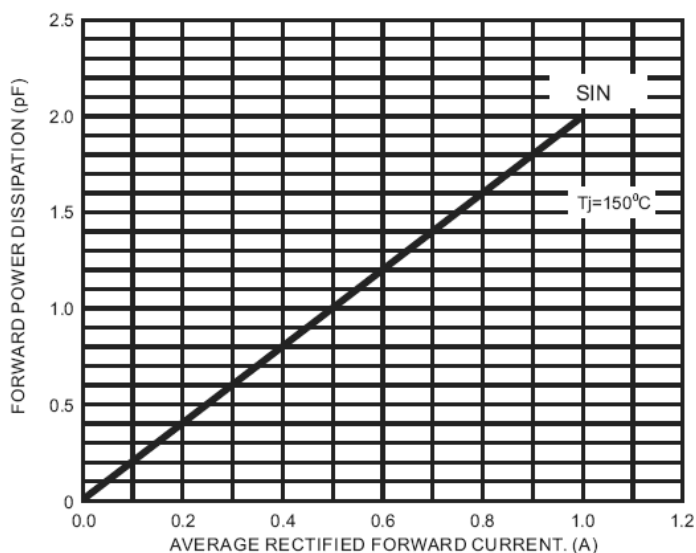


FIG.5- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

